

Is Now Part of



# **ON Semiconductor**®

# To learn more about ON Semiconductor, please visit our website at <u>www.onsemi.com</u>

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (\_), the underscore (\_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (\_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at <a href="mailto:www.onsemi.com">www.onsemi.com</a>. Please email any questions regarding the system integration to <a href="mailto:Fairchild\_questions@onsemi.com">Fairchild\_questions@onsemi.com</a>.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or unavteries, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out or i, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor and is officers, employees, uniotificated use, even if such claim any manner.



## **Features**

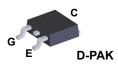
- FS Trench Technology, Positive Temperature Coefficient
- High Speed Switching
- Low Saturation Voltage: V<sub>CE(sat)</sub> =2.9 V @ I<sub>C</sub> = 5 A
- 100% of the Parts tested for  $I_{IM}(1)$
- · High Input Impedance
- RoHS Compliant

### Applications

- · Inrush current limitation
- Lighting
- · Home appliances

## **General Description**

Using novel field stop IGBT technology, Fairchild's new series of field stop 3rd generation IGBTs offer the optimum performance for inrush current limitation, lighting and home appliance applications.





#### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Description		FGD5T120SH	Unit
V <sub>CES</sub>	Collector to Emitter Voltage		1200	V
M	Gate to Emitter Voltage		±25	V
V <sub>GES</sub>	Transient Gate to Emitter Voltage		±30	V
1.	Collector Current	@ T <sub>C</sub> = 25°C	10	A
I <sup>C</sup>	Collector Current	@ T <sub>C</sub> = 100 <sup>o</sup> C	5	А
I <sub>LM</sub> (1)	Clamped Inductive Load Current	@ T <sub>C</sub> = 25°C	12.5	А
I <sub>CM</sub> (2)	Pulsed Collector Current		12.5	А
P <sub>D</sub>	Maximum Power Dissipation	@ T <sub>C</sub> = 25°C	69	W
	Maximum Power Dissipation	@ T <sub>C</sub> = 100 <sup>o</sup> C	28	W
TJ	Operating Junction Temperature		-55 to +150	°C
T <sub>stg</sub>	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes: 1. Vcc = 600 V,V\_{GE} = 15 V, I\_C = 12.5 A, R\_G = 50  $\Omega$  . Inductive Load 2. Limited by Tjmax

November 2015

	FGD51120SH -
	- 1200 V, 5 A F
-	I, 5 A FS Irench IGB I
-	

## Thermal Characteristics

Symbol	Parameter	FGD5T120SH	Unit
$R_{ extsf{ heta}JC}$ (IGBT)	Thermal Resistance, Junction to Case, Max.	1.8	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient, Max. (3)	50	°C/W

Notes: 3. Mounted on 1" squre PCB (FR4 or G-10 material)

## Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Qty per Tube
FGD5T120SH	FGD5T120SH	TO-252 A03	380 mm	16 mm	2500

## Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 uA	1200	-	-	V
$\Delta BV_{CES}$ / $\Delta T_{J}$	Temperature Coefficient of Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 uA	-	1.2	-	V/ºC
I <sub>CES</sub>	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0 V$	-	-	250	μA
I <sub>GES</sub>	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	± 400	nA
On Charac	teristics		·			
V <sub>GE(th)</sub>	G-E Threshold Voltage	$I_C = 5 \text{ mA}, V_{CE} = V_{GE}$	2.5	3.5	4.5	V
		I <sub>C</sub> = 5 A, V <sub>GE</sub> = 15 V	-	2.9	3.6	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	$I_{C} = 5 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 150^{\circ}\text{C}$	-	4.5	-	V
Dynamic C	haracteristics					
C <sub>ies</sub>	Input Capacitance		-	209	-	pF
C <sub>oes</sub>	Output Capacitance	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V, f = 1 MHz	-	11	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance		-	2	-	pF
T <sub>d(on)</sub>	Characteristics Turn-On Delay Time		-	4.8	-	ns
T <sub>r</sub>	Rise Time		-	20.8	-	ns
T <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 5 A,	-	24.8	-	ns
T <sub>f</sub>	Fall Time	R <sub>G</sub> = 30 Ω, V <sub>GE</sub> = 15 V,	-	104	-	ns
Eon	Turn-On Switching Loss	Inductive Load, T <sub>C</sub> = 25°C	-	247	-	uJ
E <sub>off</sub>	Turn-Off Switching Loss		-	94	-	uJ
E <sub>ts</sub>	Total Switching Loss		-	341	-	uJ
T <sub>d(on)</sub>	Turn-On Delay Time		-	4.8	-	ns
T <sub>r</sub>	Rise Time		-	40	-	ns
T <sub>d(off)</sub>	Turn-Off Delay Time	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 5 A,	-	25.6	-	ns
T <sub>f</sub>	Fall Time	$R_G$ = 30 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 150 <sup>o</sup> C	-	134	-	ns
E <sub>on</sub>	Turn-On Switching Loss		-	393	-	uJ
	Turn-Off Switching Loss		-	114	-	uJ
E <sub>off</sub>	Furthern ethilenning 2000			507		uJ
	Total Switching Loss		-	507	-	uJ
E <sub>ts</sub>			-	6.7	-	nC
E <sub>off</sub> E <sub>ts</sub> Q <sub>g</sub> Q <sub>ge</sub>	Total Switching Loss	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 5 A, V <sub>GE</sub> = 15 V			-	

## **Typical Performance Characteristics**



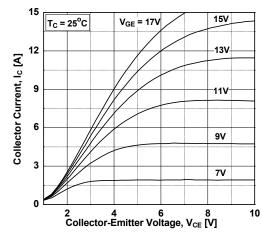


Figure 3. Typical Saturation Voltage Characteritics

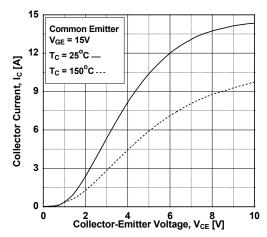


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

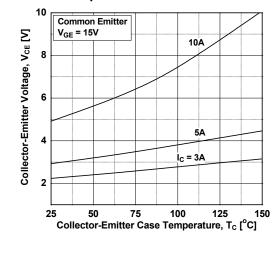
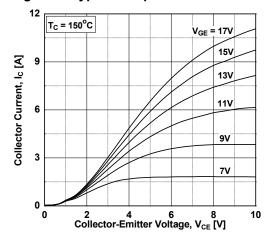


Figure 2. Typical Output Characteristics



**Figure 4. Transfer Characteristics** 

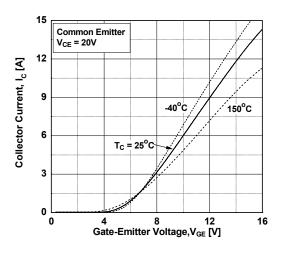
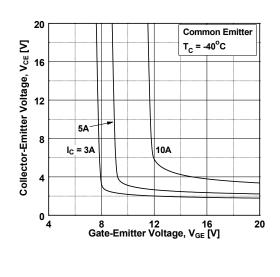
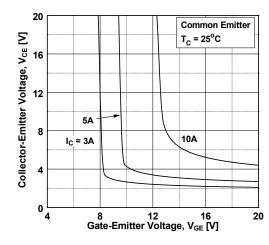


Figure 6. Saturation Voltage vs. VGE



## **Typical Performance Characteristics**

#### Figure 7. Saturation Voltage vs. VGE



**Figure 9. Capacitance Characteristics** 

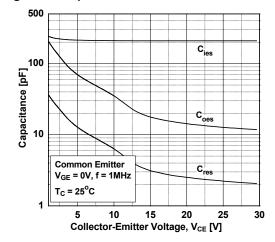


Figure 11. SOA Characteristics

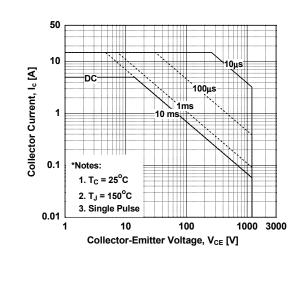
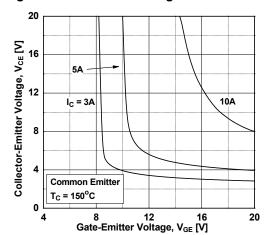


Figure 8. Saturation Voltage vs. VGE





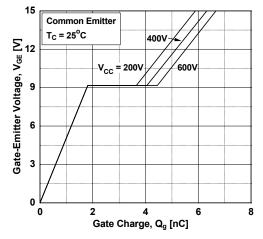
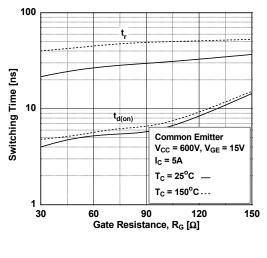


Figure 12. Turn-on Characteristics vs. Gate Resistance



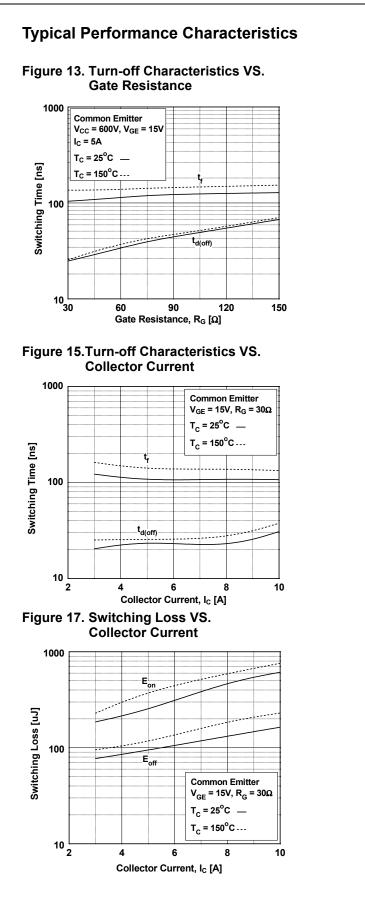


Figure 14.Turn-on Characteristics VS. Collector Current

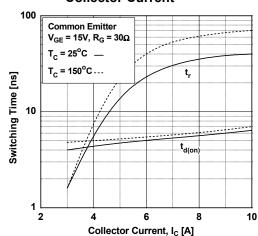
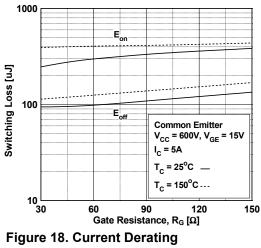
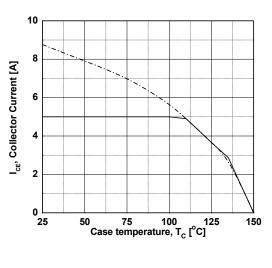
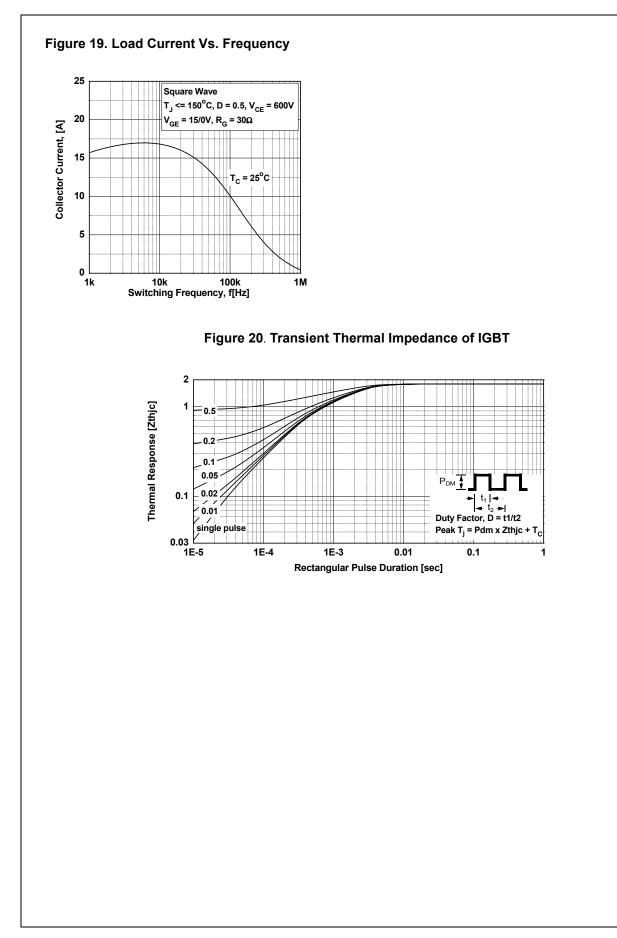
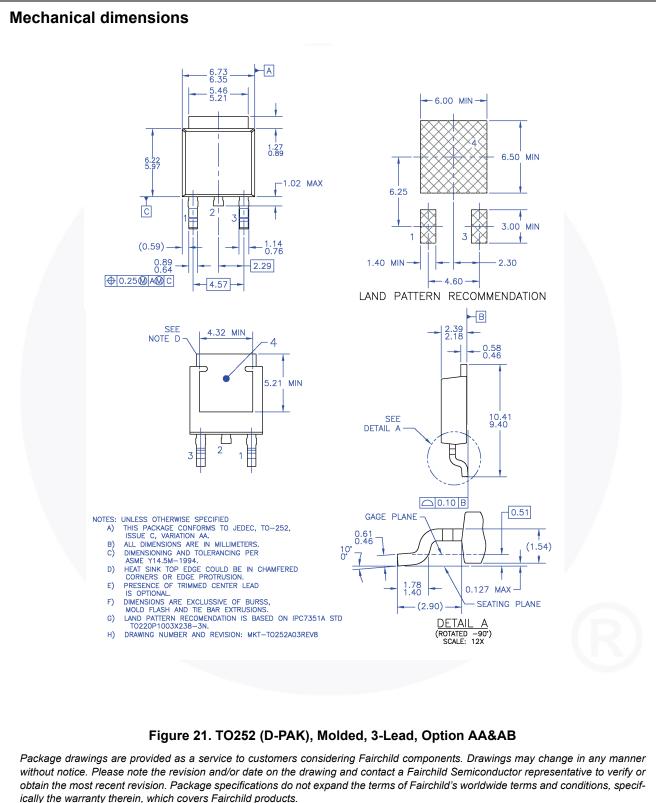


Figure 16.Switching Loss VS. Gate Resistance









Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:

http://www.fairchildsemi.com/package/packageDetails.html?id=PN\_TT252-003



#### TRADEMARKS

FAIRCHILD

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

AttitudeEngine™     FR       Awinda®     Gld       AX-CAP®*     Grn       BitSiC™     Grn       BitSiC™     Grn       Build it Now™     Grn       CorePLUS™     Grn       CorePOWER™     GT       CTL™     Intr       CUTRET Transfer Logic™     Ma       DEUXPEED®     and       Dual Cool™     Me       EcoSPARK®     Min       ESBC™     Min       Fairchild®     Mod       Fairchild Semiconductor®     Mod       FACT®     MT       FACT®     MT       Fattbench™     MV       FEBench™     MV	PFS™ RFET® lobal Power Resource <sup>SM</sup> reen FPS™ reen FPS™ e-Series™ max™ TO™ telliMAX™ OPLANAR™ arking Small Speakers Sound Louder nd Better™ egaBuck™ ICROCOUPLER™ icroFET™ icroFET™ icroFak® isroFak®	OPTOPLANAR® ® Power Supply WebDesigner™ PowerXS™ Programmable Active Droop™ QFET® QS™ Quiet Series™ RapidConfigure™ TM Saving our world, 1mW/W/kW at a time™ SignalWise™ SmartMax™ SMART START™ Solutions for Your Success™ SPM® STEALTH™ SuperFET® SuperSOT™-6 SuperSOT™-8 SuperSot™-8 SuperSot SuperSot™-8 SuperSot™-8 SuperSot™-8 SuperSot™-8 S	$\label{eq:system} \begin{split} & \ensuremath{\mathbb{E}}^{s} \\ & \ensuremath{\mathbb{E}}^{s$
---	---	---	---

\*Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

#### DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

#### AUTHORIZED USE

Unless otherwise specified in this data sheet, this product is a standard commercial product and is not intended for use in applications that require extraordinary levels of quality and reliability. This product may not be used in the following applications, unless specifically approved in writing by a Fairchild officer: (1) automotive or other transportation, (2) military/aerospace, (3) any safety critical application – including life critical medical equipment – where the failure of the Fairchild product reasonably would be expected to result in personal injury, death or property damage. Customer's use of this product is subject to agreement of this Authorized Use policy. In the event of an unauthorized use of Fairchild's product, Fairchild accepts no liability in the event of product failure. In other respects, this product shall be subject to Fairchild's Worldwide Terms and Conditions of Sale, unless a separate agreement has been signed by both Parties.

#### ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Terms of Use

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address and warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Gources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

#### PRODUCT STATUS DEFINITIONS

#### Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed Full Production		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 177

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor has against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death ass

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800–282–9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050 ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

© Semiconductor Components Industries, LLC

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for IGBT Transistors category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

748152A APT20GT60BRDQ1G APT50GT60BRG NGTB10N60FG STGFW20V60DF APT30GP60BG APT45GR65B2DU30 GT50JR22(STA1ES) TIG058E8-TL-H VS-CPV364M4KPBF NGTB25N120FL2WAG NGTG40N120FL2WG RJH60F3DPQ-A0#T0 APT40GR120B2SCD10 APT15GT120BRG APT20GT60BRG NGTB75N65FL2WAG NGTG15N120FL2WG IXA30RG1200DHGLB IXA40RG1200DHGLB APT70GR65B2DU40 NTE3320 IHFW40N65R5SXKSA1 APT70GR120J APT35GP120JDQ2 IKZA40N65RH5XKSA1 IKFW75N65ES5XKSA1 IKFW50N65ES5XKSA1 IKFW50N65EH5XKSA1 IKFW40N65ES5XKSA1 IKFW60N65ES5XKSA1 IMBG120R090M1HXTMA1 IMBG120R220M1HXTMA1 XD15H120CX1 XD25H120CX0 XP15PJS120CL1B1 IGW30N60H3FKSA1 STGWA8M120DF3 IGW08T120FKSA1 IGW75N60H3FKSA1 HGTG40N60B3 FGH60N60SMD\_F085 FGH75T65UPD STGWA15H120F2 IKA10N60TXKSA1 IHW20N120R5XKSA1 RJH60D2DPP-M0#T2 IKP20N60TXKSA1 IHW20N65R5XKSA1 IDW40E65D2FKSA1